

LQ20N200CQ Qspeed[™] Automotive Family

200 V, 20 A Common-Cathode Diode for Audio Automotive Applications

Product Summary

I _{F(AVG)} per diode	10	Α
V _{RRM}	200	V
Q _{RR} (Typ at 125 °C)	48.4	nC
I _{RRM} (Typ at 125 °C)	3.29	Α
Softness t _b /t _a (Typ at 125 °C)	0.34	

Pin Assignment



RoHS Compliant

Package uses Lead-free plating and "Green" mold compound Halogen free per IEC 61249-2-21.

Absolute Maximum Ratings

General Description

This device has the lowest Q_{RR} of any 200 V Silicon diode. Its recovery characteristics increase efficiency, reduce EMI and eliminate snubbers.

Applications

- Automotive
 - AEC-Q101 qualified
 - Fab, assembly and test certified to IATF 16949
 - ESD HBM classification H0

Features

- Low Q_{RR}, Low I_{RRM}, Low t_{RR}
- Soft recovery

Benefits

- Increases efficiency
 - Eliminates need for snubber circuits
 - Reduces EMI filter component size and count
- Enables extremely fast switching

Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Symbol	Parameter	Conditions	Rating	Units
V _{RRM}	Peak repetitive reverse voltage	T _J = 25 °C	200	V
I _{F(AVG)}	Average forward current	Per Diode, $T_J = 150$ °C, $T_C = 124$ °C	10	А
		Per Device, $T_J = 150 \text{ °C}$, $T_C = 124 \text{ °C}$	20	А
I _{FSM}	Non-repetitive peak surge current	Per Diode, 60 Hz, 1/2 cycle	100	А
$\mathrm{I}_{\mathrm{FSM}}$	Non-repetitive peak surge current	Per Diode, $\frac{1}{2}$ cycle of t = 28 μ s Sinusoid, T _c = 25 °C	350	А
Tյ	Operating junction temperature range		-40 to 150	°C
T _{STG}	Storage temperature		–55 to 150	°C
	Lead soldering temperature	Leads at 1.6mm from case, 10 sec	300	°C
P _D	Power dissipation	T _C = 25 °C	41.7	W

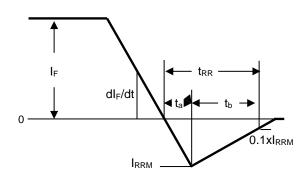
Thermal Resistance

Symbol	Resistance from:	Conditions	Rating	Units
R _{0JC} Junction to case	lunction to case	Per Diode	3.0	°C/W
	Junction to case	Per Device	1.5	°C/W

Symbol	Parameter	Conditions		Min	Тур	Max	Units
DC Chara	acteristics per diode	·					
I _R	Reverse current per diode	$V_{R} = 200 V, T_{J} =$		-	-	500	μA
		$V_{R} = 200 V, T_{J} =$		-	0.35	-	mA
V _F	Forward voltage per diode	I _F = 10 A, T _J = 25 °C		-	0.98	1.15	V
		$I_F = 10 A, T_J = 15$	50 °C	-	0.85	-	V
CJ	Junction capacitance per diode	V _R = 10 V, 1 MHz		-	38	-	pF
Dynamic	Characteristics per dio	de					
t _{RR}	per diode V _R =	$dI_F/dt = 200 \text{ A/}\mu\text{s}$	T _J = 25 °C	-	16	-	ns
		$V_{R} = 130 V,$ $I_{F} = 10 A$	T _J = 125 °C	-	23.5	-	ns
Q _{RR}	Reverse recovery charge,	$dI_F/dt = 200 \text{ A/}\mu\text{s}$	T _J = 25 °C	-	20	32	nC
	per diode	$V_{R} = 130 V,$ $I_{F} = 10 A$	T _J = 125 °C	-	48.4	-	nC
I _{RRM}	Maximum reverse	$dI_F/dt = 200 \text{ A}/\mu\text{s}$	T _J = 25 °C	-	2.1	3.05	А
recovery current, per diode	$V_{R} = 130 V,$ $I_{F} = 10 A$	T _J = 125 °C	-	3.29	-	A	
S	a s th	$dI_F/dt = 200 \text{ A}/\mu\text{s}$	T _J = 25 °C	-	0.41	-	
Softness per diode = $\frac{t_b}{t_a}$	$V_{R} = 130 V,$ $I_{F} = 10 A$	T _J = 125 °C	-	0.34	-		

Electrical Specifications at $T_J = 25 \text{ °C}$ (unless otherwise specified)

Note to component engineers: Q-Series diodes employ Schottky technologies in their design and construction. Therefore, component engineers should plan their test setups to be similar to traditional Schottky test setups. (For further details, see application note AN-300.)



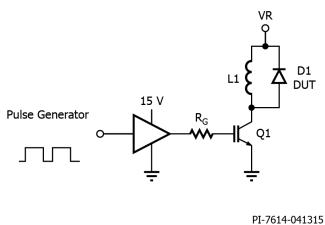
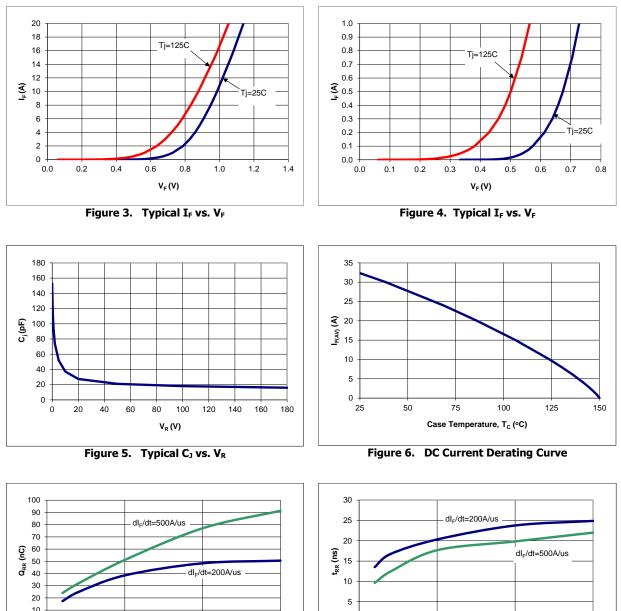


Figure 1. Reverse Recovery Definitions









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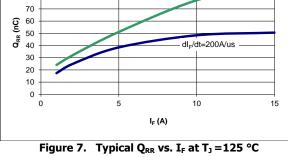
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10

 $I_F(A)$

Figure 8. Typical t_{RR} vs. I_F at T_J =125 °C

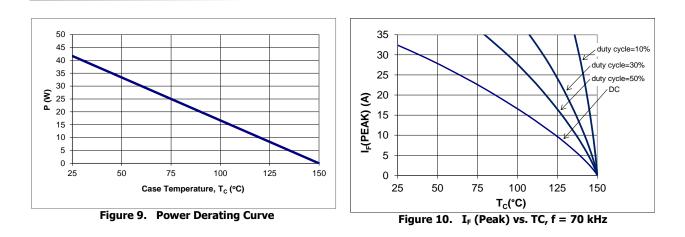
Electrical Specifications at T₁ = 25 $^{\circ}$ C (unless otherwise specified)





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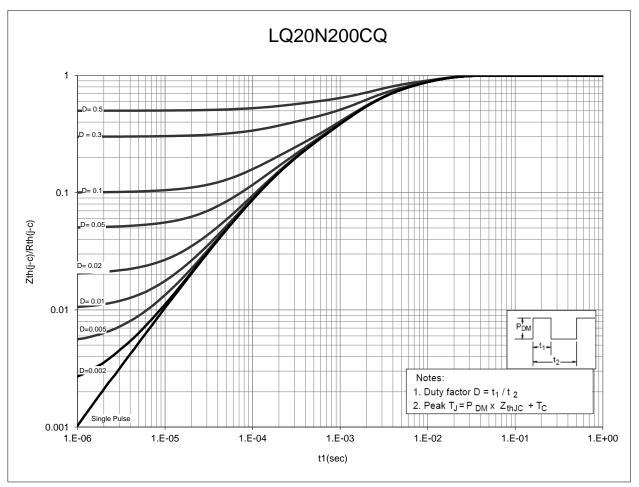


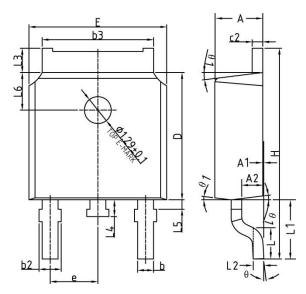
Figure 11. Normalized Maximum Transient Thermal Impedance





Dimensional Outline Drawings

TO-252 DPAK



	Millimeters		
Dim	MIN	MAX	
Α	2.20	2.38	
A1	0	0.10	
A2	0.90	1.10	
b	0.72	0.85	
b2	0.72	0.90	
b3	5.13	5.46	
c2	0.47	0.60	
D	6.00	6.20	
Е	6.50	6.70	
е	2.186	2.386	
н	9.80	10.40	
L	1.40	1.70	
L1	2.90	REF	
L2	0.51	BSC	
L3	0.90	1.25	
L4	0.60	1.00	
L5	0.15	0.75	
L6	1.80 REF		
Θ	0°	8°	
01	5°	9°	



Soldering time and temperature: This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

Ordering Information

Part Number	Package	Packing
LQ20N200CQ	TO-252 DPAK	2500 units/reel

The information contained in this document is subject to change without notice.





Revision	Notes	Date
1.1	Code A release.	03/19





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Power Integrations Worldwide Sales Support Locations

WORLD HEADQUARTERS

5245 Hellyer Avenue San Jose, CA 95138, USA. Main: +1-408-414-9200 Customer Service: Worldwide: +1-65-635-64480 Americas: +1-408-414-9621 e-mail: usasales@power.com

CHINA (SHANGHAI)

Rm 2410, Charity Plaza, No. 88, North Caoxi Road, Shanghai, PRC 200030 Phone: +86-21-6354-6323

e-mail: chinasales@power.com

CHINA (SHENZHEN)

17/F, Hivac Building, No. 2, Keji Nan 8th Road, Nanshan District, Shenzhen, China, 518057 Phone: +86-755-8672-8689 e-mail: chinasales@power.com GERMANY (AC-DC/LED Sales) Einsteinring 24 85609 Dornach/Aschheim Germany Tel: +49-89-5527-39100 e-mail: eurosales@power.com

GERMANY (Gate Driver Sales)

HellwegForum 1 59469 Ense Germany Tel: +49-2938-64-39990 e-mail: igbt-driver.sales@ power.com

INDIA

#1, 14th Main Road Vasanthanagar Bangalore-560052 India Phone: +91-80-4113-8020 e-mail: indiasales@power.com

ITALY

Via Milanese 20, 3rd. Fl. 20099 Sesto San Giovanni (MI) Italy Phone: +39-024-550-8701 e-mail: eurosales@power.com

JAPAN

Yusen Shin-Yokohama 1-chome Bldg. 1-7-9, Shin-Yokohama, Kohoku-ku Yokohama-shi, Kanagawa 222-0033 Japan Phone: +81-45-471-1021 e-mail: japansales@power.com

KOREA

RM 602, 6FL Korea City Air Terminal B/D, 159-6 Samsung-Dong, Kangnam-Gu, Seoul, 135-728 Korea Phone: +82-2-2016-6610 e-mail: koreasales@power.com

SINGAPORE

51 Newton Road, #19-01/05 Goldhill Plaza Singapore, 308900 Phone: +65-6358-2160 e-mail: singaporesales@power.com

TAIWAN

5F, No. 318, Nei Hu Rd., Sec. 1 Nei Hu District Taipei 11493, Taiwan R.O.C. Phone: +886-2-2659-4570 e-mail: taiwansales@power.com

UK

Building 5, Suite 21 The Westbrook Centre Milton Road Cambridge CB4 1YG Phone: +44 (0) 7823-557484 e-mail: eurosales@power.com





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